VB40170C

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Vishay General Semiconductor

Dual High Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.52$ V at $I_F = 5$ A



DESIGN SUPPORT TOOLS



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 20 A			
V _{RRM}	170 V			
I _{FSM}	200 A			
V_F at $I_F = 20$ A	0.68 V			
T _J max.	175 °C			
Package	D ² PAK (TO-263AB)			
Circuit configuration	Common cathode			

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C



 Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: D²PAK (TO-263AB) Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/N-M3 - halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 and M3 suffix meet JESD 201 class 2 whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER		SYMBOL	VB40170C	UNIT		
Maximum repetitive peak reverse voltage		V _{RRM}	170	V		
Maximum average forward rectified current (fig. 1)	per device		40	А		
	per diode	IF(AV)	20	A		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load			200	А		
Voltage rate of change (rated V _R)			10 000	V/µs		
Operating junction and storage temperature range		T _J , T _{STG}	-40 to +175	°C		

ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F ⁽¹⁾	0.66	-	V	
	I _F = 10 A			0.75	-		
	I _F = 20 A			0.86	1.20		
	I _F = 5 A	T _A = 125 °C		0.52	-		
	I _F = 10 A			0.59	-		
	I _F = 20 A			0.68	0.76		
Reverse current per diode	V _R = 136 V	T _A = 25 °C		1.3	-	μA	
		T _A = 125 °C	I _R ⁽²⁾	2.2	-	mA	
	V _R = 170 V	T _A = 25 °C	'R (=)	-	250	μA	
		T _A = 125 °C		4.2	50	mA	

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: pulse width \leq 5 ms

 Revision: 20-Jun-2018
 1
 Document Number: 89949

 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
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THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	VB40170C	UNIT	
Typical thermal resistance	per diode	R _{θJC} ⁽¹⁾	1.2	°C/W	
	per device	n _θ JC ⁽¹⁾	0.85		

Note

 $^{(1)}$ Mounted on infinite heat sink; thermal resistance $R_{\theta JC}$ - junction-to-case

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AB	VB40170C-E3/4W	1.38	4W	50/tube	Tube	
TO-263AB	VB40170C-E3/8W	1.38	8W	800/reel	Tape and reel	
TO-263AB	VB40170C-M3/I	1.38	I	800/reel	13" diameter plastic tape and reel	

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

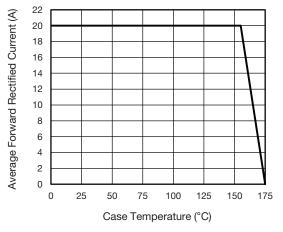


Fig. 1 - Maximum Forward Current Derating Curve

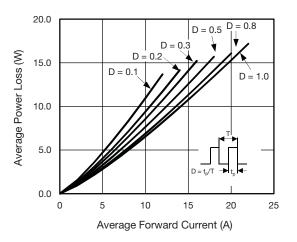


Fig. 2 - Forward Power Loss Characteristics Per Diode

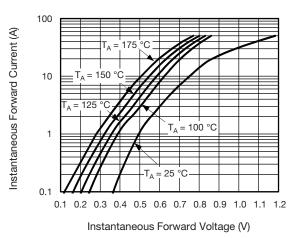
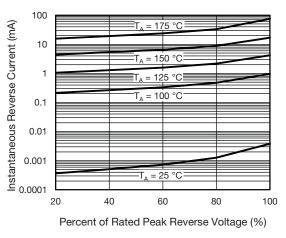
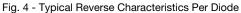


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode





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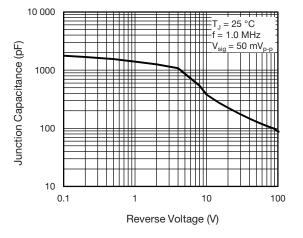


Fig. 5 - Typical Junction Capacitance Per Diode

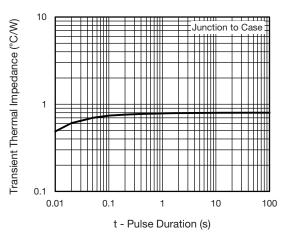
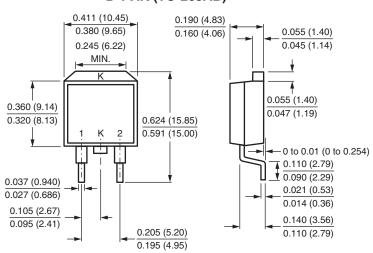


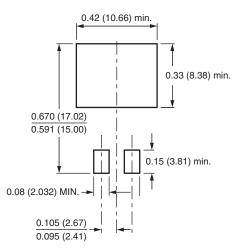
Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



D²PAK (TO-263AB)

Mounting Pad Layout





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Revision: 01-Jan-2025

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